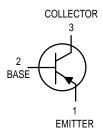
# **Chopper Transistor** PNP Silicon



#### **MAXIMUM RATINGS**

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	VCEO	-35	Vdc
Collector-Base Voltage	VCBO	-40	Vdc
Emitter-Base Voltage	VEBO	-25	Vdc
Collector Current — Continuous	IC	-150	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	1.5 12	Watts mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	R <sub>0</sub> JA <sup>(1)</sup>	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta}JC$	83.3	°C/W

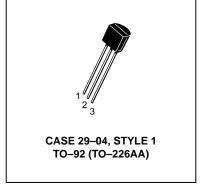
# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25$ °C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage <sup>(2)</sup> $(I_C = -10 \text{ mAdc}, I_B = 0)$	V(BR)CEO	-35	_	Vdc
Collector-Base Breakdown Voltage (I <sub>C</sub> = -10 μAdc, I <sub>E</sub> = 0)	V(BR)CBO	-40	_	Vdc
Emitter-Base Breakdown Voltage ( $I_E = -10 \mu Adc, I_C = 0$ )	V(BR)EBO	-25	_	Vdc
Collector Cutoff Current (V <sub>CB</sub> = -10 Vdc, I <sub>E</sub> = 0)	ICBO	_	-100	nAdc
Emitter Cutoff Current (VBE = -10 Vdc, IC = 0)	IEBO	_	-100	nAdc

2. Pulse Test: Pulse Width  $\leq~300~\mu\text{s},$  Duty Cycle  $\leq~2.0\%.$ 

MPS404A

**Motorola Preferred Device** 



Preferred devices are Motorola recommended choices for future use and best overall value.



### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS				
DC Current Gain ( $I_C = -12 \text{ mAdc}$ , $V_{CE} = -0.15 \text{ Vdc}$ )	hFE	30	400	_
Collector-Emitter Saturation Voltage ( $I_C = -12 \text{ mAdc}$ , $I_B = -0.4 \text{ mAdc}$ ) ( $I_C = -24 \text{ mAdc}$ , $I_B = -1.0 \text{ mAdc}$ )	VCE(sat)	_ _ _	-0.15 -0.2	Vdc
Base-Emitter Saturation Voltage ( $I_C = -12 \text{ mAdc}$ , $I_B = -0.4 \text{ mAdc}$ ) ( $I_C = -24 \text{ mAdc}$ , $I_B = -1.0 \text{ mAdc}$ )	V <sub>BE(sat)</sub>	_ _	-0.85 -1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Common–Base Cutoff Frequency ( $I_C = -1.0 \text{ mAdc}$ , $V_{CB} = 6.0 \text{ Vdc}$ )	fob	4.0	_	MHz
Output Capacitance (V <sub>CB</sub> = -6.0 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>obo</sub>	l	20	pF

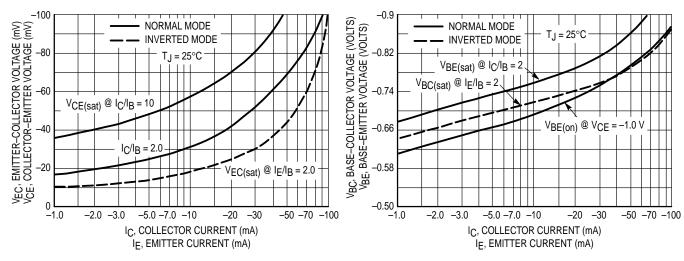


Figure 1. Collector-Emitter Voltage

Figure 2. Base "On" Voltage

## **NORMAL MODE** 200 100 hFE, DC CURRENT GAIN 80 60 -55°C 40 30 20 10 -1.0 -2.0 -3.0-5.0 -7.0 -10 -30 -50 -70 -100 IC, COLLECTOR CURRENT (mA)

Figure 3. DC Current Gain @ V<sub>CE</sub> = −0.15 Vdc

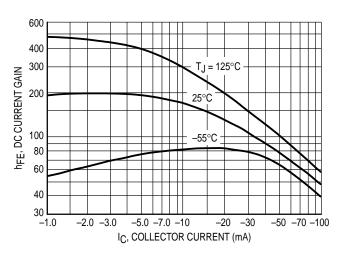


Figure 5. DC Current Gain @  $V_{CE} = -1.0 \text{ Vdc}$ 

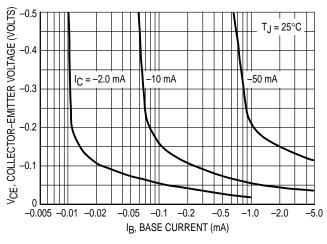


Figure 7. Collector Saturation Region

#### **INVERTED MODE**

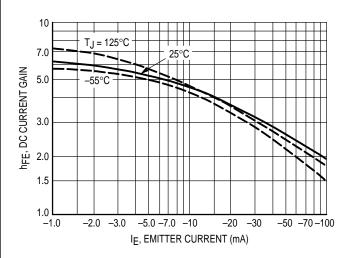


Figure 4. DC Current Gain @  $V_{EC} = -0.15 \text{ Vdc}$ 

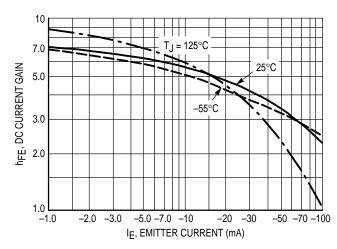


Figure 6. DC Current Gain @ V<sub>EC</sub> = −1.0 Vdc

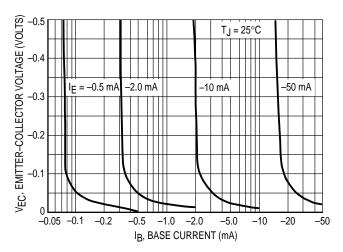


Figure 8. Emitter Saturation Region

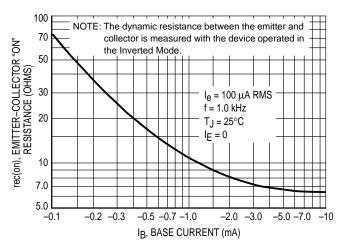


Figure 9. Emitter-Collector "On" Resistance

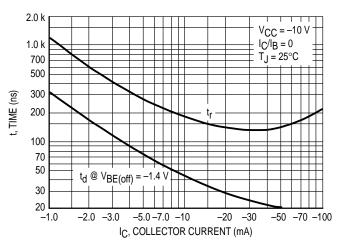
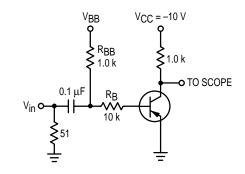


Figure 11. Turn-On Time



	V <sub>in</sub> (Volts)	V <sub>BB</sub> (Volts)
ton, td and tr	-12	+1.4
toff, ts and tf	+20.6	-11.6

Voltages and resistor values shown are for  $I_C = 10$  mA.  $I_C/I_B = 10$  and  $I_{B1} = I_{B2}$ . Resistor values changed to obtain curves in Figures 11 and 12.

Figure 13. Switching Time Test Circuit

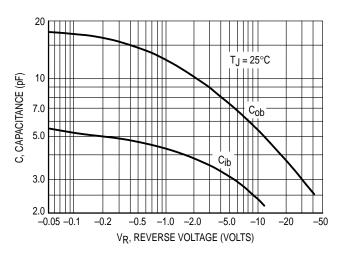


Figure 10. Capacitance

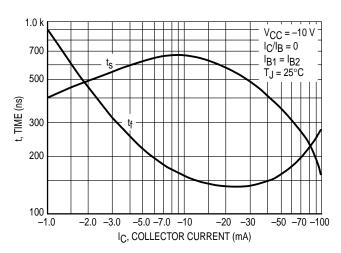


Figure 12. Turn-Off Time

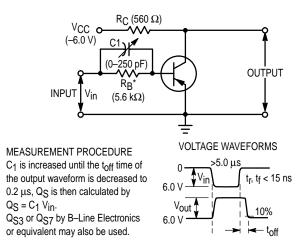
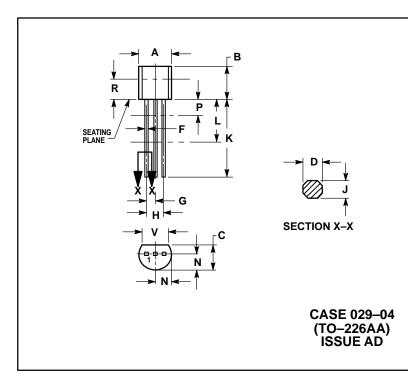


Figure 14. Stored Base Charge Test Circuit

### **PACKAGE DIMENSIONS**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. CONTROUL OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION DAND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135	_	3.43	

STYLE 1: PIN 1. EMITTER

2. BASE 3. COLLECTOR

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